## NSN 5961-01-011-3906

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-011-3906 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Overall Diameter:** 0.130 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 regulator voltage **Voltage Tolerance In Percent:** -2.0/+5.0 **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig: A110a0